

# UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

## Dual Common Base-Collector Bias Resistor Transistors

### NPN and PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. These digital transistors are designed to replace a single device and its external resistor bias network. The BRT eliminates these individual components by integrating them into a single device. In the UMC2NT1G series, two complementary BRT devices are housed in the SOT-353 package which is ideal for low power surface mount applications where board space is at a premium.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Available in 8 mm, 7 inch/3000 Unit Tape and Reel
- AEC-Q101 Qualified and PPAP Capable
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant\*

**MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted, common for  $Q_1$  and  $Q_2$ , - minus sign for  $Q_1$  (PNP) omitted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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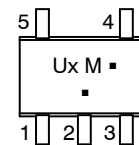
<http://onsemi.com>



SC-88A/SOT-353  
CASE 419A  
STYLE 6



#### MARKING DIAGRAM



Ux = Device Marking  
x = 2, 3 or 5  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

**MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted, common for  $Q_1$  and  $Q_2$ , – minus sign for  $Q_1$  (PNP) omitted)

Rating	Symbol	Value	Unit
<b>THERMAL CHARACTERISTICS</b>			
Thermal Resistance – Junction-to-Ambient (surface mounted)	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
Total Package Dissipation @ $T_A = 25^\circ\text{C}$ (Note 1)	$P_D$	150	mW

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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## Q1 TRANSISTOR: PNP

### OFF CHARACTERISTICS

Collector-Base Cutoff Current ( $V_{CB} = 50\text{ V}, I_E = 0$ )	$I_{CBO}$	–	–	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50\text{ V}, I_B = 0$ )	$I_{CEO}$	–	–	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0, I_C = 0\text{ mA}$ ) UMC2NT1G, NSVUMC2NT1G UMC3NT1G, NSVUMC3NT1G UMC5NT1G/T2G, NSVUMC5NT2G	$I_{EBO}$	–	–	0.2 0.5 1.0	mAdc

### ON CHARACTERISTICS

Collector-Base Breakdown Voltage ( $I_C = 10\ \mu\text{A}, I_E = 0$ )	$V_{(BR)CBO}$	50	–	–	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 2.0\text{ mA}, I_B = 0$ )	$V_{(BR)CEO}$	50	–	–	Vdc
DC Current Gain ( $V_{CE} = 10\text{ V}, I_C = 5.0\text{ mA}$ ) UMC2NT1G, NSVUMC2NT1G UMC3NT1G, NSVUMC3NT1G UMC5NT1G/T2G, NSVUMC5NT2G	$h_{FE}$	60 35 20	100 60 35	– – –	
Collector-Emitter Saturation Voltage ( $I_C = 10\text{ mA}, I_B = 0.3\text{ mA}$ )	$V_{CE(SAT)}$	–	–	0.25	Vdc
Output Voltage (on) ( $V_{CC} = 5.0\text{ V}, V_B = 2.5\text{ V}, R_L = 1.0\text{ k}\Omega$ )	$V_{OL}$	–	–	0.2	Vdc
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}, V_B = 0.5\text{ V}, R_L = 1.0\text{ k}\Omega$ )	$V_{OH}$	4.9	–	–	Vdc
Input Resistor UMC2NT1G UMC3NT1G UMC5NT1G/T2G	R1	15.4 7.0 3.3	22 10 4.7	28.6 13 6.1	k $\Omega$
Resistor Ratio UMC2NT1G UMC3NT1G UMC5NT1G/T2G	R1/R2	0.8 0.8 0.38	1.0 1.0 0.47	1.2 1.2 0.56	

**UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G,  
NSVUMC5NT2G**

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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**Q2 TRANSISTOR: NPN  
OFF CHARACTERISTICS**

Collector-Base Cutoff Current ( $V_{CB} = 50\text{ V}$ , $I_E = 0$ )	$I_{CBO}$	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )	$I_{CEO}$	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0$ , $I_C = 0\text{ mA}$ )	$I_{EBO}$				mAdc
UMC2NT1G		-	-	0.2	
UMC3NT1G		-	-	0.5	
UMC5NT1G/T2G		-	-	0.1	

**ON CHARACTERISTICS**

Collector-Base Breakdown Voltage ( $I_C = 10\ \mu\text{A}$ , $I_E = 0$ )	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 2.0\text{ mA}$ , $I_B = 0$ )	$V_{(BR)CEO}$	50	-	-	Vdc
DC Current Gain ( $V_{CE} = 10\text{ V}$ , $I_C = 5.0\text{ mA}$ )	$h_{FE}$				
UMC2NT1G		60	100	-	
UMC3NT1G		35	60	-	
UMC5NT1G/T2G		80	140	-	
Collector-Emitter Saturation Voltage ( $I_C = 10\text{ mA}$ , $I_B = 0.3\text{ mA}$ )	$V_{CE(SAT)}$	-	-	0.25	Vdc
Output Voltage (on) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 2.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )	$V_{OL}$	-	-	0.2	Vdc
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )	$V_{OH}$	4.9	-	-	Vdc
Input Resistor	R1				$\text{k}\Omega$
UMC2NT1G		15.4	22	28.6	
UMC3NT1G		7.0	10	13	
UMC5NT1G/T2G		33	47	61	
Resistor Ratio	R1/R2				
UMC2NT1G		0.8	1.0	1.2	
UMC3NT1G		0.8	1.0	1.2	
UMC5NT1G/T2G		0.8	1.0	1.2	

# UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

## ORDERING INFORMATION

Device	Package	Shipping†
UMC2NT1G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
NSVUMC2NT1G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
UMC3NT1G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
NSVUMC3NT1G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
UMC3NT2G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
UMC5NT1G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
UMC5NT2G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel
NSVUMC5NT2G	SC-88A/SOT-353 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## DEVICE MARKING AND RESISTOR VALUES

Device	Marking	Transistor 1 - PNP		Transistor 2 - NPN	
		R1 (K)	R2 (K)	R1 (K)	R2 (K)
UMC2NT1G, NSVUMC2NT1G	U2	22	22	22	22
UMC3NT1G, NSVUMC3NT1G	U3	10	10	10	10
UMC3NT2G	U3	10	10	10	10
UMC5NT1G	U5	4.7	10	47	47
UMC5NT2G, NSVUMC5NT2G	U5	4.7	10	47	47

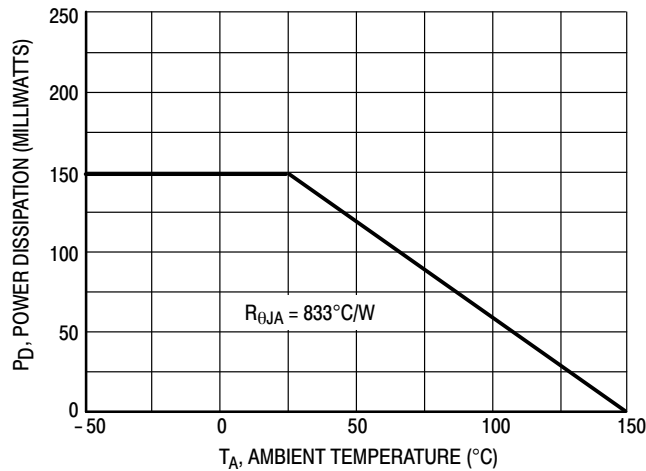
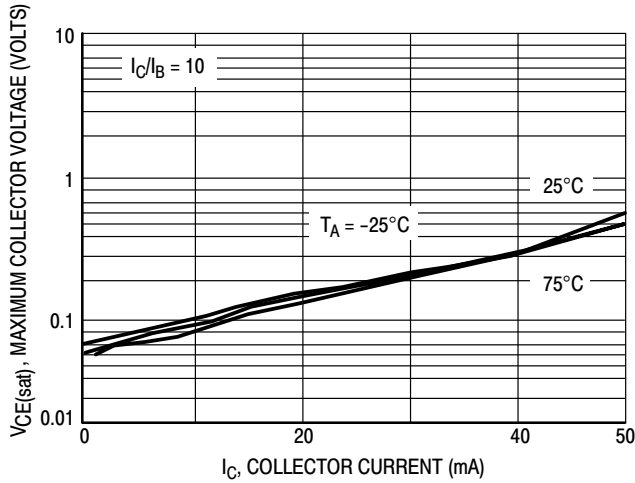


Figure 1. Derating Curve

**UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G**

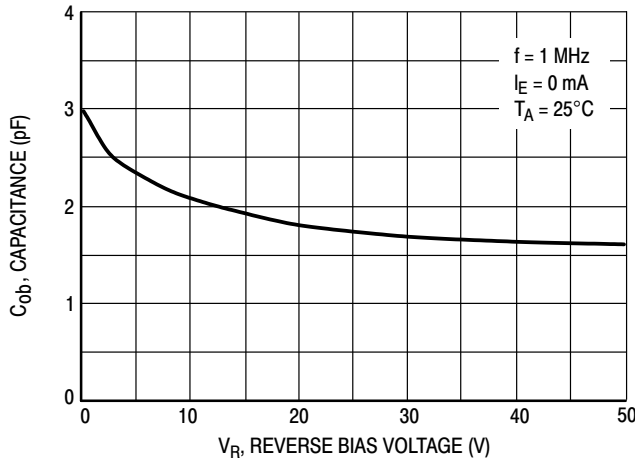
**TYPICAL ELECTRICAL CHARACTERISTICS — UMC2NT1G, NSVUMC2NT1G PNP TRANSISTOR**



**Figure 2.  $V_{CE(sat)}$  versus  $I_C$**



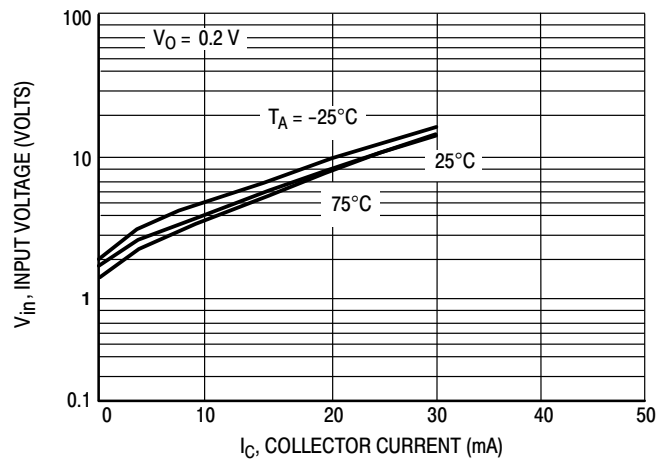
**Figure 3. DC Current Gain**



**Figure 4. Output Capacitance**



**Figure 5. Output Current versus Input Voltage**



**Figure 6. Input Voltage versus Output Current**

**UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G**

**TYPICAL ELECTRICAL CHARACTERISTICS — UMC2NT1G, NSVUMC2NT1G NPN TRANSISTOR**



**Figure 7.  $V_{CE(sat)}$  versus  $I_C$**



**Figure 8. DC Current Gain**



**Figure 9. Output Capacitance**



**Figure 10. Output Current versus Input Voltage**



**Figure 11. Input Voltage versus Output Current**

UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

TYPICAL ELECTRICAL CHARACTERISTICS — UMC3NT1G PNP TRANSISTOR

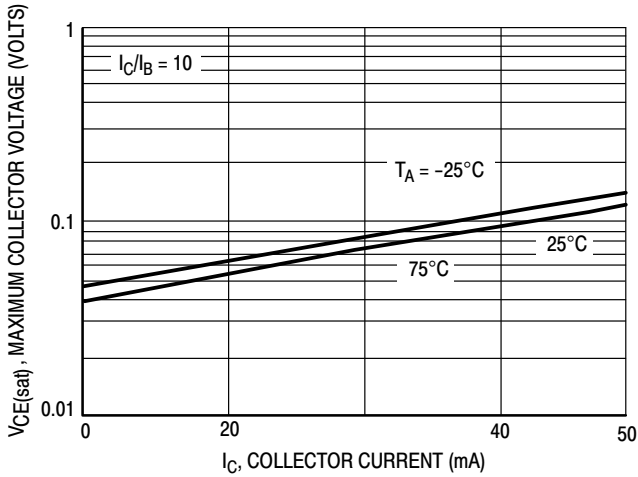


Figure 12.  $V_{CE(sat)}$  versus  $I_C$

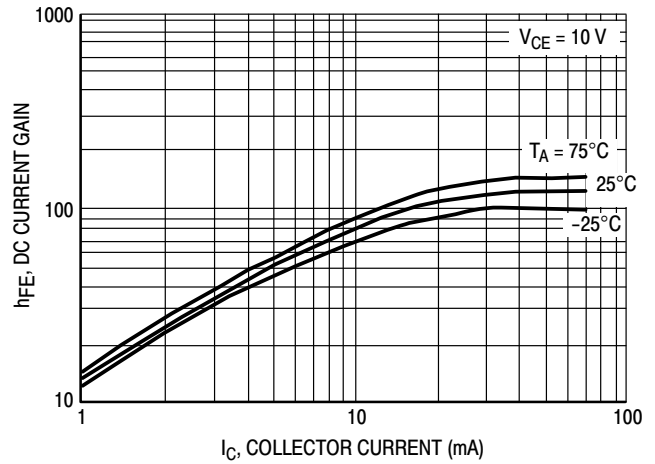


Figure 13. DC Current Gain

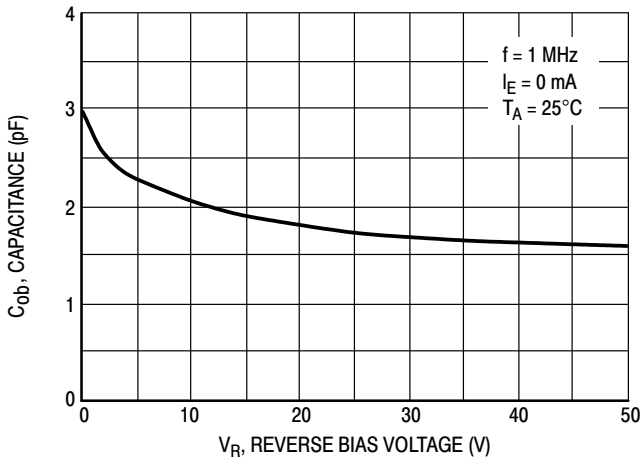


Figure 14. Output Capacitance

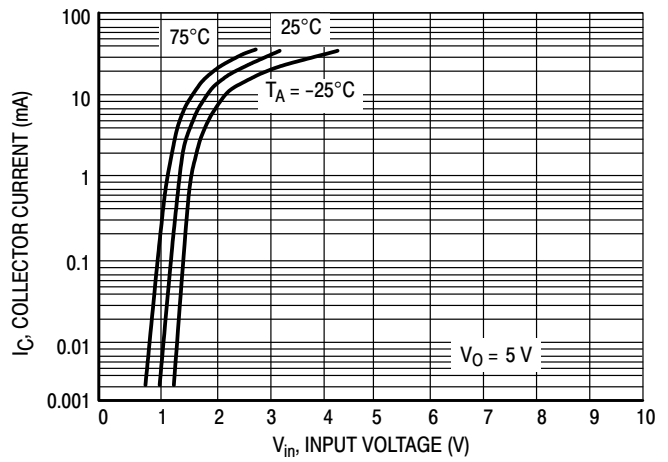


Figure 15. Output Current versus Input Voltage

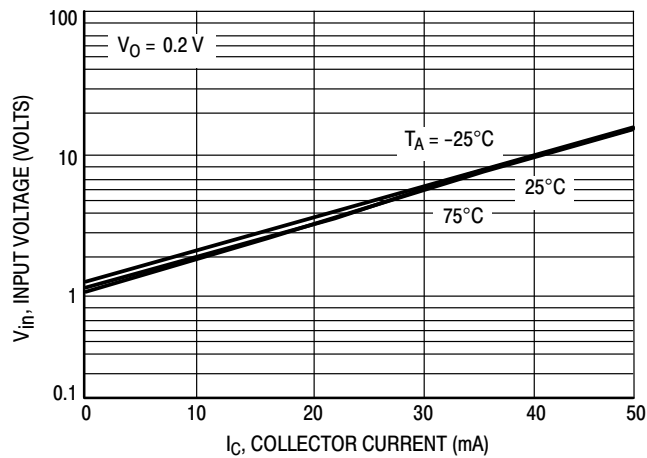


Figure 16. Input Voltage versus Output Current

UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

TYPICAL ELECTRICAL CHARACTERISTICS — UMC3NT1G NPN TRANSISTOR

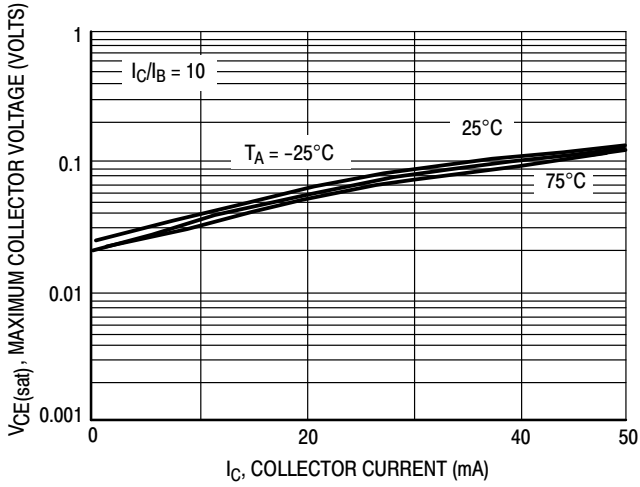


Figure 17.  $V_{CE(sat)}$  versus  $I_C$



Figure 18. DC Current Gain

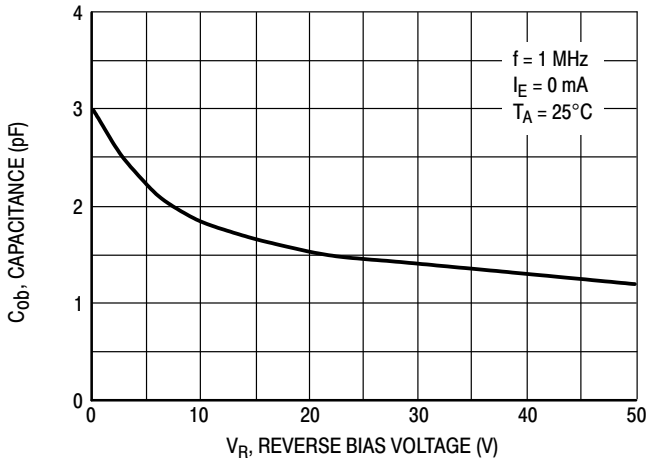


Figure 19. Output Capacitance

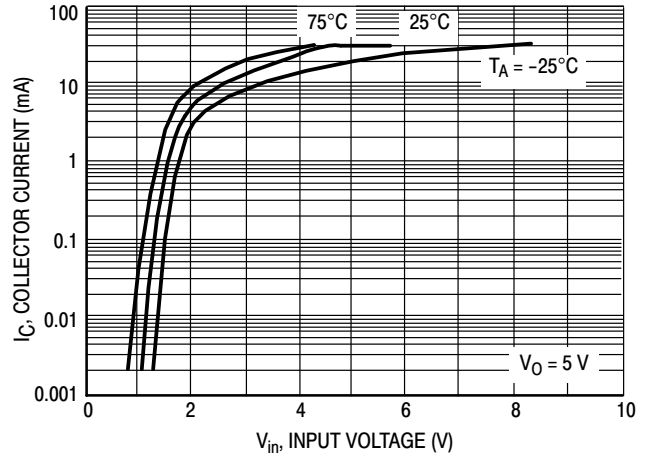


Figure 20. Output Current versus Input Voltage



Figure 21. Input Voltage versus Output Current



UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

TYPICAL ELECTRICAL CHARACTERISTICS — UMC5NT1G PNP TRANSISTOR



Figure 22.  $V_{CE(sat)}$  versus  $I_C$

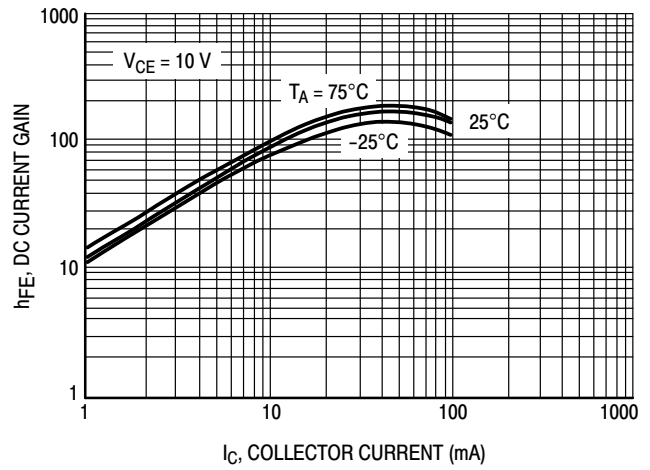


Figure 23. DC Current Gain



Figure 24. Output Capacitance

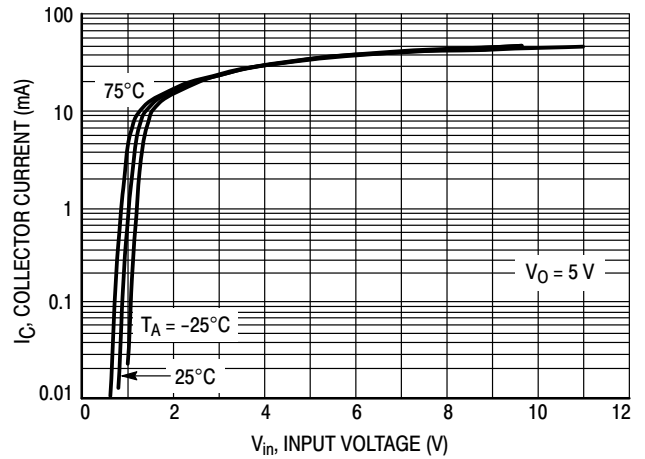


Figure 25. Output Current versus Input Voltage

UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

TYPICAL ELECTRICAL CHARACTERISTICS — UMC5NT1G NPN TRANSISTOR

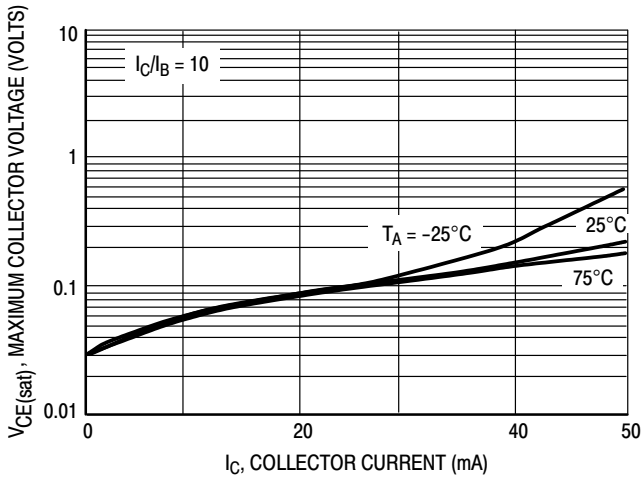


Figure 26.  $V_{CE(sat)}$  versus  $I_C$

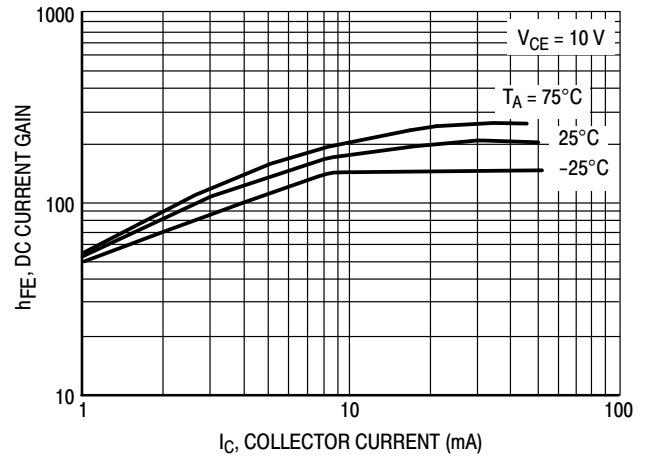


Figure 27. DC Current Gain

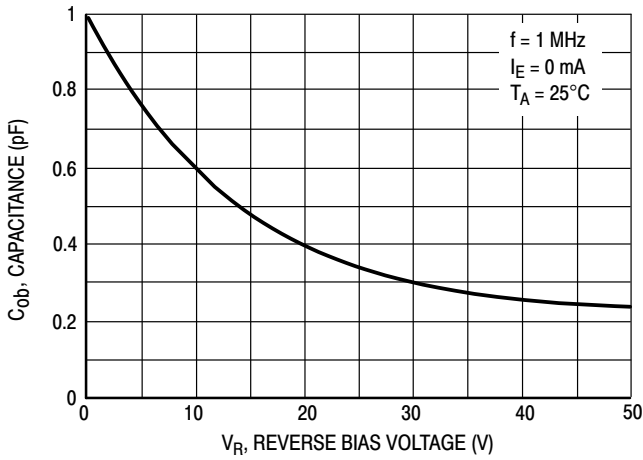


Figure 28. Output Capacitance



Figure 29. Output Current versus Input Voltage

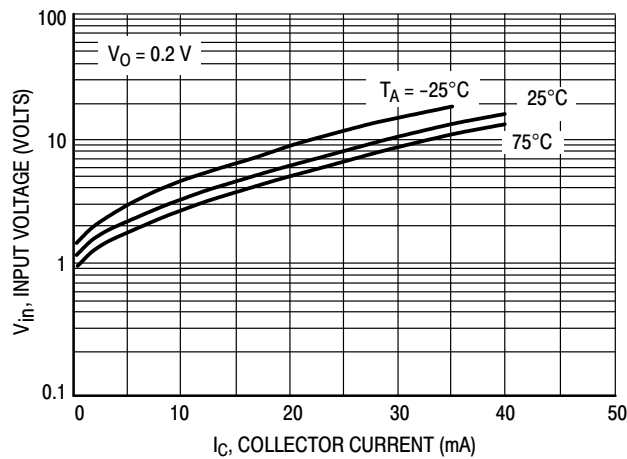


Figure 30. Input Voltage versus Output Current

# UMC2NT1G, NSVUMC2NT1G, UMC3NT1G, NSVUMC3NT1G, UMC5NT1G, NSVUMC5NT2G

## PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353)  
CASE 419A-02  
ISSUE K



NOTES:

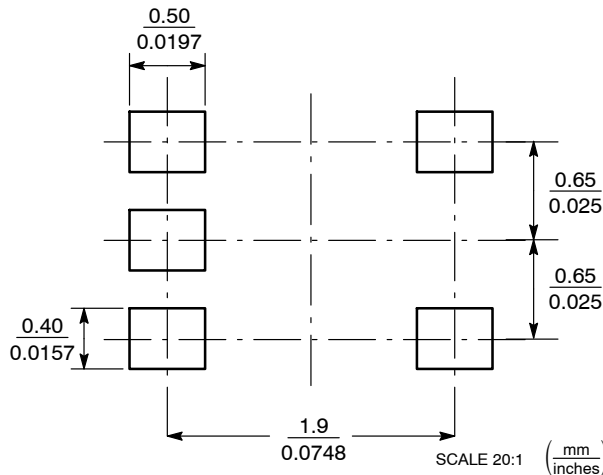
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

STYLE 6:

- PIN 1. EMITTER 2
- BASE 2
- EMITTER 1
- COLLECTOR
- COLLECTOR 2/BASE 1

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
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- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
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- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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## JONHON

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(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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